IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: §	
§	
MOSHE GEFEN ET AL. §	
§	
Serial No.: 09/816,459 §	
§	
Filed: March 26, 2001 §	Group Art Unit: 2186
§	
For: USING NON-EXECUTABLE MEMORY AS §	
EXECUTABLE MEMORY §	Attorney
§	Docket: 246/67
Examiner: Yamir Encarnacion §	

Commissioner of Patents and Trademarks
Washington, DC 20231

RESPONSE TRANSMITTAL

Sir:

(1) Applicant is a:
   _X_ small entity   ___ verified statement attached
                _X_ verified statement filed
   ___ other than small entity

(2) The fee for claims 37 CFR1.16(b)-(d) has been calculated as shown below:

FOR:	CLAIMS ON FILE	AMENDED CLAIMS	SMALL ENTITY RATE	FEE	OR	OTHER THAN A SMALL ENTITY - RATE	FEE
TOTAL CLAIMS	9	22	2 x 9=	$ 18	OR	x 18=	$
	3	5	2 x 42=	$ 84	OR	x 84=	$
			TOTAL	$102	OR	TOTAL	$

(3) An amendment   _X_ is filed herewith
               ____ has been filed

(4) Please charge the extension fee and any other amount required to Deposit Account No. 06-2140.
    A duplicate copy of this form is enclosed.

Respectfully submitted,

Mark M. Friedman
Attorney for Applicant
Registration No. 33,883

Date: December 8, 2002

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MEMORY AS EXECUTABLE § Docket: 246/67
MEMORY §
§
Examiner: Yamir Encarnacion §

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Washington, DC 20231

RESPONSE

Sir:

This is in response to the United States Patent and Trademark Office Action mailed October 7, 2001, which response is being made on or before January 7, 2002 and for which no extension fees are due. Please amend the above-identified application as follows:

In the Specification:

Please replace the paragraph beginning on page 8 line 10 with the following rewritten paragraph:

--1.   The 1KB of SRAM is executable and satisfies the requirements of an executable memory (Random Access and standard memory interface). A CPU or executing entity **12** can therefore execute any location within the range of the SRAM **10**. According to the present invention, at any given time, the 1KB of SRAM **10** contains up to 1KB from the